### Features

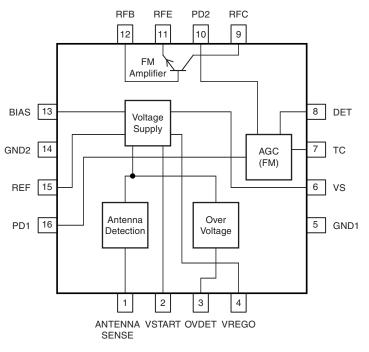
- Highly Integrated All-in-one Active Antenna IC
- Operating Frequency Range: 50 to 900MHz
  - Main Application 76 to 108MHz (Broadcast FM Worldwide)
- Integrated AGCIntegrated Driver for PIN Diodes
- Integrated Power Supply Regulator
- Integrated Antenna Sensor
- High Dynamic Range
- Excellent Noise Performance
- High Intercept Point 3rd Order
- RF Amplifier Adjustable to Various Cable Impedances
- Low Noise Output Voltage
- Low Power Consumption

## 1. Description

The Atmel<sup>®</sup> ATR4253 is a highly integrated high-performance IC for active antenna amplification. The device has a built-in AGC, antenna detection, a power supply regulator and two driver stages for external PIN diodes.

The Atmel ATR4253 is based on BICMOS technology. The device is designed in particular for car applications and is suitable for active antennas located in several positions within the car such as bumpers, windscreen, mirrors or windows.

#### Figure 1-1. Block Diagram





Integrated Circuit Solution for Active Antennas

# Atmel ATR4253

# Summary

**NOTE:** This is a summary document. The complete document is available under NDA. For more information, please contact your local Atmel sales office.

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## 2. Pin Configuration

#### Figure 2-1. Pinning VQFN 3x3 / 16 Pins

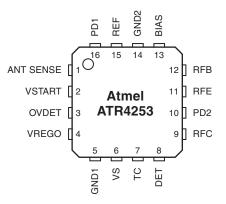


Table 2-1.Pin Description

Pin	Symbol	Function
1	ANT SENSE	Antenna sense input
2	VSTART	Comparator input of voltage detector
3	OVDET	Overvoltage detection input
4	VREGO	Voltage regulator output
5	GND1	Ground voltage regulator
6	VS	Supply voltage
7	TC	AGC time constant
8	DET	AGC level detector input
9	RFC	Amplifier Collector (NPN)
10	PD2	2 <sup>nd</sup> AGC output for pin diode
11	RFE	Amplifier emitter (NPN)
12	RFB	Amplifier base (NPN)
13	BIAS	Bias voltage (2.7V)
14	GND2	Ground FM
15	REF	Reference voltage (6V)
16	PD1	1 <sup>st</sup> FM AGC output for pin diode
Paddle	GND	Ground paddle

#### 3. Functional Description

The Atmel<sup>®</sup> ATR4253 is a highly integrated antenna amplifier with a broad range of features and functions. It compensates cable losses between the antenna and the car radio, which is usually placed far away from the antenna. The device can be used in the frequency range of 50 up to 900MHz (i.e. FM, DAB (+), DMB, DVB-T, ISDB-T, etc.) and has the flexibility to address different antenna types (e.g., glass, windscreen, roof antennas).

A separate automatic gain control (AGC) function is integrated in order to avoid overdriving the RF amplifier at large signal conditions.

The integrated PIN diode drivers help to reduce the external component cost and to minimize the board space.

The external component cost can be further reduced as the voltage regulation stage is also integrated. This stage provides overvoltage protection and current limitation. An external transistor is used as power driver for this stage.

#### 3.1 RF Amplifier Stage

The RF amplifier is realized with a high-performance NPN transistor. This allows the use of an amplifier configuration which is optimized for the individual application requirements. For low-cost applications, the common emitter configuration enables good performance at reasonable BOM cost. For high-end applications, a common base configuration with transformer feedback provides high IP3 and low noise figures at reasonable current consumption. In both configurations, gain, input and output impedance can be adjusted by modifying the external components.

The bias voltage (BIAS) for the base of the NPN transistor is derived from an integrated voltage reference and has a PTAT (proportional to absolute temperature) behavior. The bias current of the RF amplifier is defined by an external resistor and is kept constant over temperature.

#### 3.2 AGC

The IC is equipped with an AGC functionality to prevent overdriving the amplifier in case the amplifier is operated at strong antenna signals, e.g., near transmitters. It is possible to realize an additional antenna amplifier path with integrated AGC and external RF transistor. The bandwidth of the integrated AGC circuit is 900MHz.

The amplifier output (RFC) is connected to a capacitive voltage divider and the divided signal is applied to the AGC level detector at pin DET. This level detector input is optimized for low distortion. The rectified signal is compared against an internal reference. The divider ratio of the external voltage divider defines the AGC's threshold. If the threshold is reached, pin PD1 drives a positive current through one or two external pin diodes in shunt configuration. In case the limiting range of the shunt configuration is not sufficient, an additional pin diode in serial configuration can be added and controlled via pin PD2. The current from PD2 through the serial pin diode is opposite to the current of PD1. This helps to limit the amplifier input signal and thus to prevent the FM amplifier from signal overdrive.

The drivers required for the external pin diode(s) are built-in into the ATR4253 IC, which reduces the BOM cost and the application size.





#### 3.3 Supply Voltage Regulator

The driving voltage for an external power transistor is provided by an integrated regulator circuit.

An overvoltage protection circuit detects overvoltage condition and switches off the amplifier and AGC circuit in order to reduce current consumption and avoid thermal overload.

#### 3.4 Antenna Sensor

The Atmel<sup>®</sup> ATR4253 provides a built-in antenna sensor that detects if the antenna is properly connected to the amplifier module. If no antenna is detected, the amplifier and AGC circuit are switched off to signal this error via supply current reduction to the unit that provides and monitors the supply current for the antenna amplifier (e.g., the car radio).

## 4. Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Pin	Symbol	Min.	Max.	Unit
Supply voltage	6	Vs	-0.3	+12	V
Antenna sense current	1	ANT SENSE	-500	+500	μA
Comparator input current	2	VSTART	0	2	mA
Overvoltage detector	3	OVDET	-0.3	+3.3	V
Collector of FM amplifier	9	RFC	3	16	V
Power dissipation		P <sub>tot</sub>		700	mW
Junction temperature		Τ <sub>i</sub>		150	°C
Ambient temperature		T <sub>amb</sub>	-40	+115	°C
Storage temperature		T <sub>stg</sub>	-50	+150	°C
ESD HBM	All	V <sub>HBM</sub>	-2	+2	kV

### 5. Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient, soldered on PCB, dependent on PCB layout	R <sub>thJA</sub>	40	K/W

## 6. Operating Range

Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	Normal operation	6	Vs	7.5	10	11	V
Supply voltage	Performance may be reduced, no malfunction	6	V <sub>S</sub>	7		11	V
FM emitter current	Thermal condition	11	I <sub>RFE</sub>			35	mA





## 7. Electrical Characteristics

 $V_{S}$  = 10 V,  $T_{amb}$  = 25°C, unless otherwise specified.

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*
		AGC OFF	VS	ls		12		mA	В
		AGC ON ; includes 7 mA pin diode current	VS	ls		19		mA	В
1.1	Supply current	$T_{amb} = -40$ to +115°C; AGC ON; includes 7mA pin diode current and 31mA RF current	VS, RFC	ls, I <sub>RFC</sub>		50	70	mA	С
2	RF Amplifier								
2.3	Supply current <sup>(1)</sup>	Common base	RFC	I <sub>RFC</sub>		31		mA	В
2.4	Supply current <sup>(2)</sup>	Common emitter	RFC	I <sub>RFC</sub>		35		mA	Α
2.6	Input resistance	f = 100MHz	RF IN	R <sub>FMIN</sub>		50		Ω	С
2.7	Output resistance	f = 100MHz	RF OUT	R <sub>FMOUT</sub>		50		Ω	С
2.8	Power gain	f = 100MHz	RF IN, RF OUT	G		5.2		dB	С
2.9	OIP3 at FMOUT	Common base	RF OUT			146		dBµV	С
2.10	NF	Common base	RF OUT			1.6		dB	С
2.11	Power gain	f = 100MHz, common emitter	RF OUT	G		13.5		dB	В
2.12	OIP3 at FMOUT	Common emitter	RF OUT			140		dBµV	В
2.13	NF	Common emitter	RF OUT			3.5		dB	С
2.14	Maximum operating frequency	3dB corner, common emitter	RF OUT		450			MHz	С
3	AGC		1						L.
3.4	Maximum pin diode current	AGC active, 115°C	PD1		12	19		mA	D
3.5	Maximum pin diode current	AGC not active	PD2		12			mA	А
3.6	Input resistance		DET	R <sub>DET</sub>	17		25	kΩ	С
3.7	Input capacitance	f = 100MHz	DET	C <sub>DET</sub>	1.5		2.0	pF	С
4	Voltage Regulator / I	Monitor	1						L.
4.1	Output voltage of regulator	Battery voltage $V_B = 14V$	VS		9.5	10	10.5	V	А
4.2	Ripple rejection of regulator	100Hz, V <sub>B</sub> > V <sub>S</sub> + 1V	VB, RF OUT		40	50		dB	С

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Notes: 1. Current defined by R11=  $68\Omega$ 

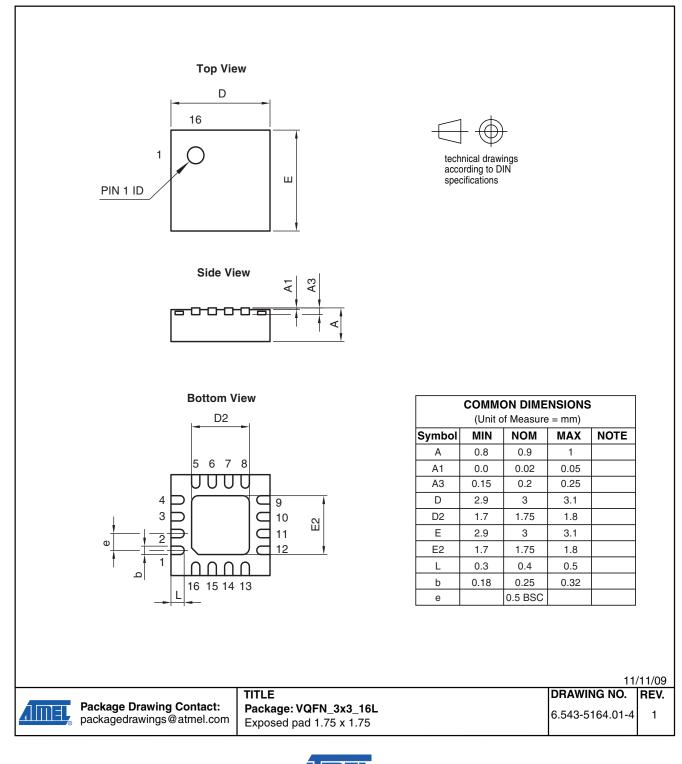
2. Current defined by R11=  $56\Omega$ 

# Atmel ATR4253

### 8. Ordering Information

Extended Type Number	Package	Remarks
ATR4253-PVPW	VQFN 3x3 / 16L	Taped on reel, 2k volume
ATR4253-PVQW	VQFN 3x3 / 16L	Taped on reel, 8k volume

## 9. Package Information





## **10. Revision History**

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.

Revision No.	History
9194CS-AUDR-10/10	Ordering Information table changed
9194BS-AUDR-09/10	Section 6 "Operating Range" on page 5 changed



Atmel Corporation

2325 Orchard Parkway San Jose, CA 95131 USA Tel: (+1)(408) 441-0311 Fax: (+1)(408) 487-2600 Atmel Asia Limited Unit 01-5 & 16, 19/F BEA Tower, Millennium City 5 418 Kwun Tong Road Kwun Tong, Kowloon HONG KONG Tel: (+852) 2245-6100 Fax: (+852) 2722-1369

#### Atmel Munich GmbH

Business Campus Parkring 4 D-85748 Garching b. Munich GERMANY **Tel:** (+49) 89-31970-0 **Fax:** (+49) 89-3194621

#### Atmel Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 JAPAN **Tel:** (+81) (3) 3523-3551 **Fax:** (+81) (3) 3523-7581

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